

## Electronic and Optical Excitations in Confined Nanostructures: Density Functional versus Many-body Methods

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- Introduction
  - Achievements and Deficiencies of DFT
  - Many-Body Theory Alternative to DFT
- GW & BSE for Electronic and Optical Excitations
  - Levels of Approximation
  - Excitons
- Examples (Benzene, Si<sub>n</sub>H<sub>m</sub>)
- Comparison of Many-Body vs DFT methods for Ag Clusters

Outline

- $\blacktriangleright \Delta SCF vs GW$
- TDLDA vs BSE



## Collaborators



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M. Tiago

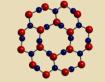


J. C. Idrobo



### K.Baishya



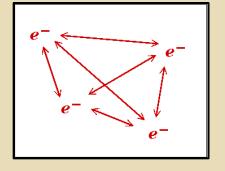


Self-consistent mean-field theory.

A generic electronic system is fully described by a single scalar function, the electron density *n*(**r**).

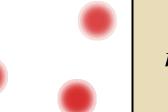
Formally exact.

In practice, the exchangecorrelation functional is modeled.



**Ψ>** 







 Good description of weakly correlated, homogeneous systems.

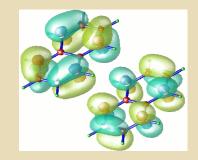


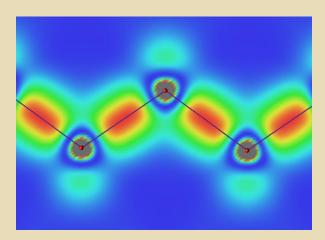
### Achievements of DFT



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- First-principles electronic band theory.
- Quantum molecular dynamics.
- Quantum chemistry.







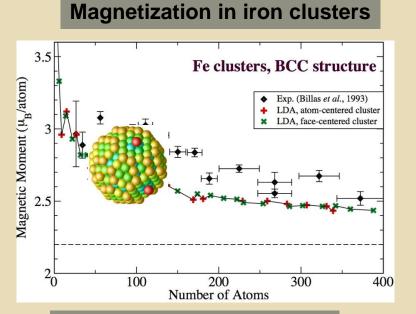
In 1998, Walter Kohn shared the Nobel Prize in Chemistry, "for his development of the density-functional theory".



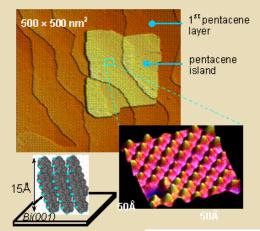
### Achievements of DFT



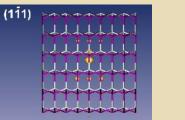
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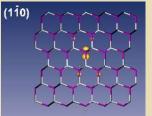


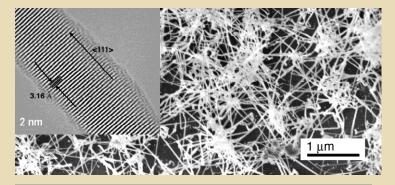
#### **Growth of organic crystals**



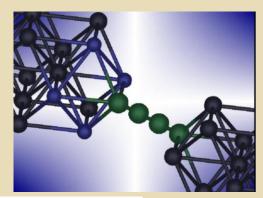
#### Doped semiconductor nanowires



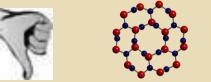




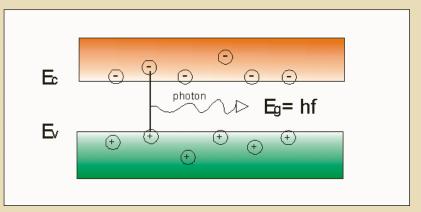
#### **Transport through nanojunctions**







- Exchange-correlation functional cannot be improved systematically.
- Complex magnetic ordering is still a challenge.
- Band gap is systematically underestimated.
- It does not give excitation energies: no optical spectroscopy.







## Yes! Many

## Many-body Green's function methods

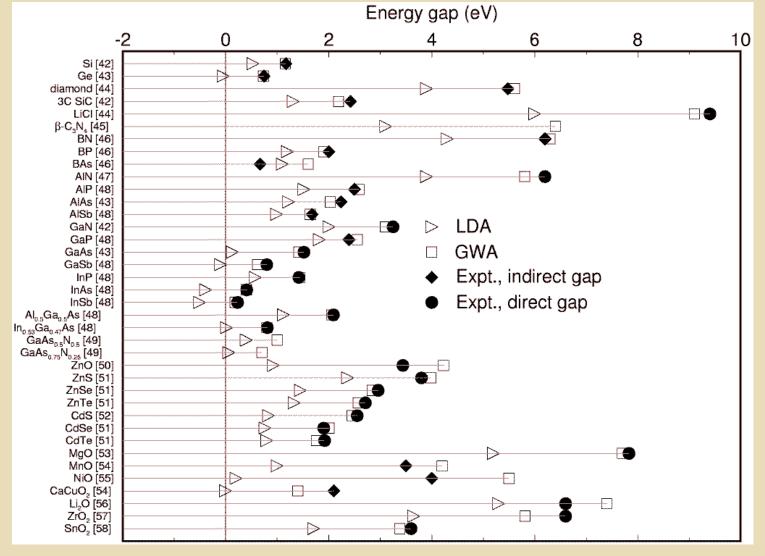
U Gives band gap greatly improved from DFT.

- Does not require phenomenological parameters.
- Exact. If you manage to sum up all Feynman diagrams.
- Amenable to high-performance computing.

#### **Band gaps of semiconductors**

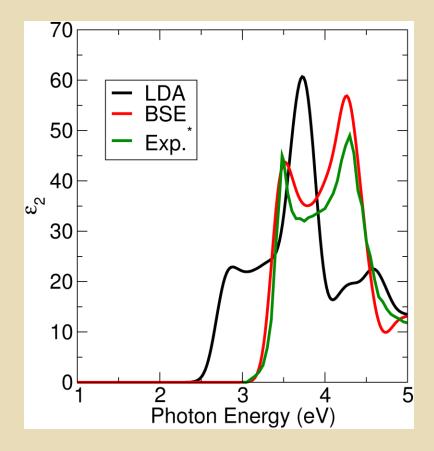


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Compiled by Aulbur, Jönsson, Wilkins, Solid State Phys. 54, 1(2000)





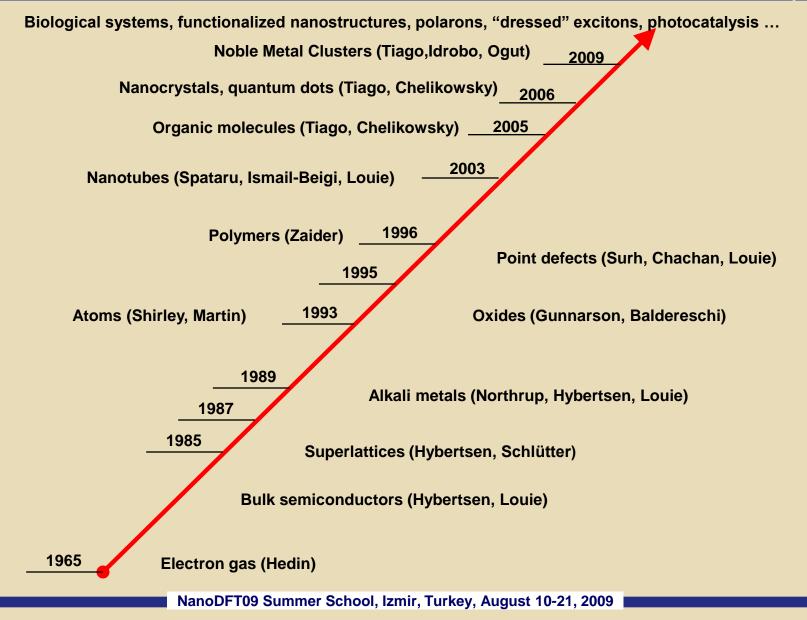
	Egap	$\Gamma^{v}_{25'} \rightarrow \Gamma^{c}_{15}$	$\Gamma^{v}_{25'} \rightarrow X^{c}_{1}$
DFT	0.46	2.52	0.60
GW <sup>†</sup>	1.29	3.35	1.44
Exp.*	1.17	3.35	1.3

<sup>†</sup> Hybertsen and Louie (1986). \*Lautenschlager *et al.* (1987).

Photoluminescence
Exciton dynamics
Photoemission spectroscopy
Transport in doped materials







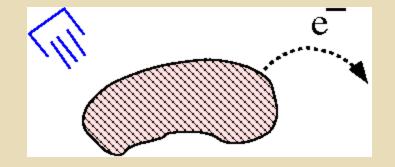




#### Quasi-particle approximation:

$$G(\mathbf{r},\mathbf{r}';E) = \sum_{n} \frac{\varphi_n(\mathbf{r})\varphi_n^{\star}(\mathbf{r}')}{E - \varepsilon_n}$$

In DFT:



Eigenvalue problem:

UIC

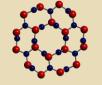
$$\begin{bmatrix} -\frac{\hbar^2}{2m} \nabla^2 + V_{ion} + V_H + \Sigma \end{bmatrix} \varphi_n(\mathbf{r}) = \varepsilon_n \varphi_n(\mathbf{r})$$
$$\begin{bmatrix} -\frac{\hbar^2}{2m} \nabla^2 + V_{ion} + V_H + V_{xc} \end{bmatrix} \psi_n(\mathbf{r}) = E_n \psi_n(\mathbf{r})$$

Perturbation theory:

$$[H_{DFT} + \Sigma - V_{xc}] \varphi_n = \varepsilon_n \varphi_n$$



Requirements



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1. DFT Green's function:

$$G_0(\mathbf{r}, \mathbf{r}'; E) = \sum_n \frac{\psi_n(\mathbf{r})\psi_n^{\star}(\mathbf{r}')}{E - E_n}$$

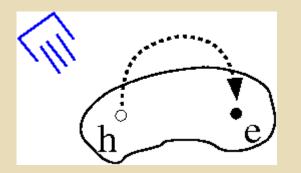
sum over occupied and unoccupied energy levels

- 2.  $G_0W_0$  and  $G_0W_f$  approximations rely on DFT as a "good starting point".
- 3. Local, dynamic dielectric screening must be known.

$$W \approx \epsilon^{-1} \frac{e^2}{|\mathbf{r} - \mathbf{r}'|}$$







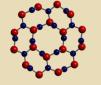
Eigenvalue problem:

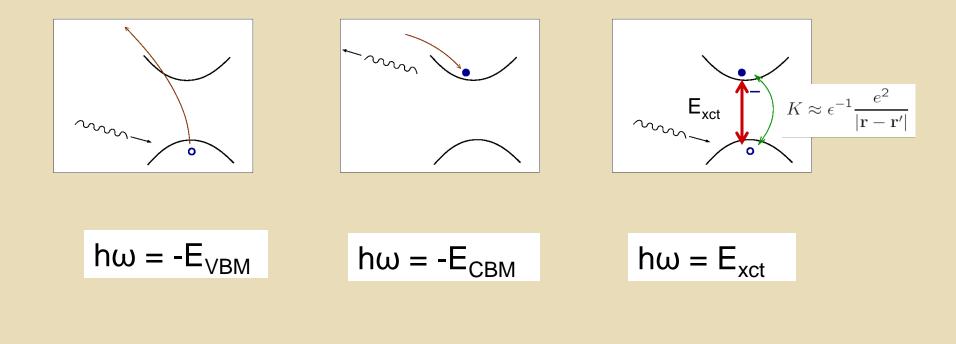
$$\left(\varepsilon_{c}^{GW} - \varepsilon_{v}^{GW}\right) A_{cv}^{S} + \sum_{c'v'} \langle vc | K^{BSE} | c'v' \rangle A_{c'v'}^{S} = \Omega^{S} A_{cv}^{S}$$

- Many-body expansion of the electron-hole propagator.
- Dynamics of electron-hole excitation obtained by solving the Bethe-Salpeter equation (BSE).
- Requires knowledge of quasiparticle orbitals (get from GW).







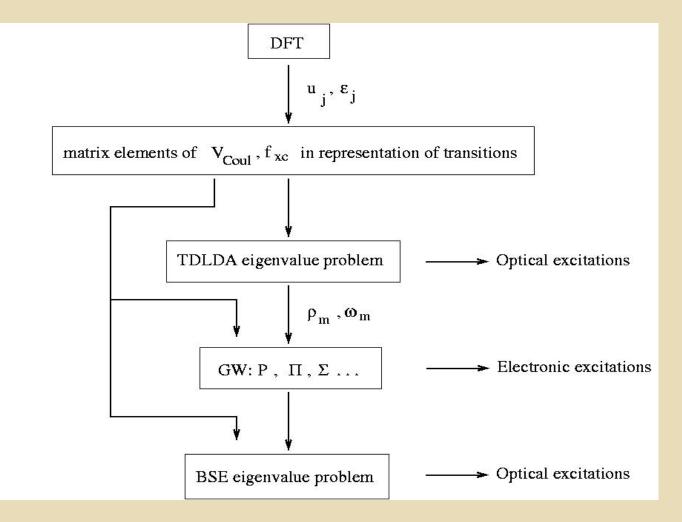


Exciton binding energy :  $(E_{CBM} - E_{VBM}) - E_{xct} > 0$ 





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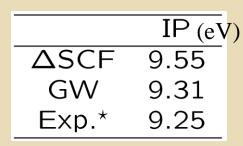
#### **RGWBS** Package (free software)

Benzene,  $C_6H_6$ 



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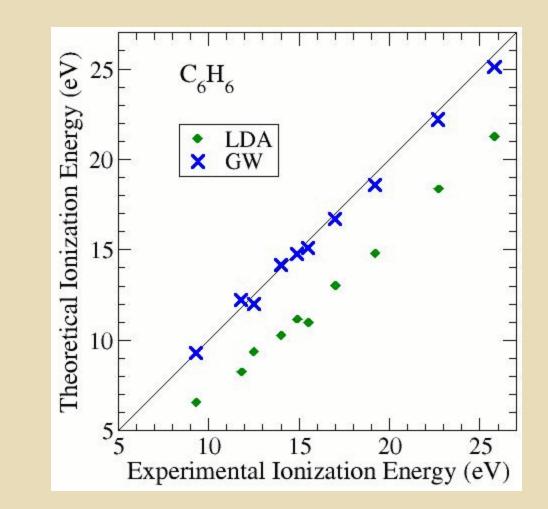
#### 1<sup>st</sup> Ionization Potential:



\* Koch & Otto (1972).

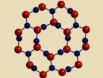
**Electron Affinity:** 

EA (eV) ΔSCF -GW -0.99 Exp.\* -1.12



\* Resonant transmission: Barrow *et al.* (1987).





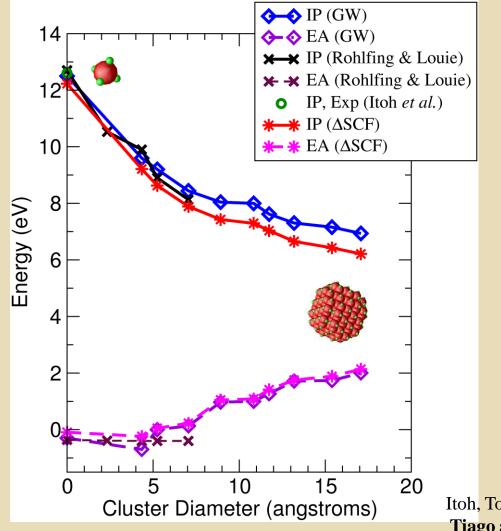
		TDLDA	BSE	Exp.*	(eV)
Triplet	$B_{1u}$	4.53	3.59	3.9	
Singlet	$B_{2u}$	5.40	4.86	5.0	dark
	$B_{1u}$	6.23	6.14	6.2	dark
	$E_{1u}$	6.9-7.2	7.23	6.9	bright

\* Resonant transitions: Doering *et al.* (1969).

Low-energy excitations are better described within BSE.Strong electron-hole binding is missing in TDLDA excitations.



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## $\Sigma$ = i **GW**Γ<sub>LDA</sub>

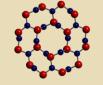
- $\triangle$ SCF predicts the correct EA.
- IP differs by ~0.7 eV:

•self-interaction effects;

•wrong asymptotic behaviour of  $V_{xc}$ .

• Same trend in Si nanoshells  $(Si_{156}H_{184})$ 

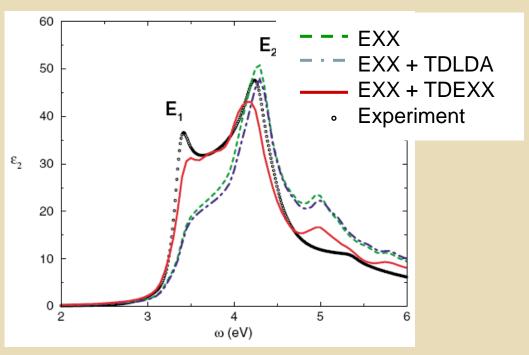
Rohlfing & Louie, Phys. Rev. Lett. **80**, 3320 (1998) Itoh, Toyoshima & Onuki, J. Chem. Phys. **85**, 4867 (1986) **Tiago and Chelikowsky, Phys. Rev. B 73, 205334 (2006)** 



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• Two of the state-of-the-art computational techniques for calculating optical excitations in materials: Time-dependent linear response theory using DFT (TDDFT) and adiabatic LDA (TDLDA), and Green's function many-body perturbation methods such as GW+Bethe-Salpeter Equation (GWBSE).

 Computational demand for TDLDA considerably smaller compared to GWBSE.
 GWBSE, however, gives much more accurate excitation energies in extended systems (excitonic effects).



Kim and Görling, PRL (2002)





The two methods mostly applied to *sp*-bonded clusters with considerable success.

### **OUR GOAL**

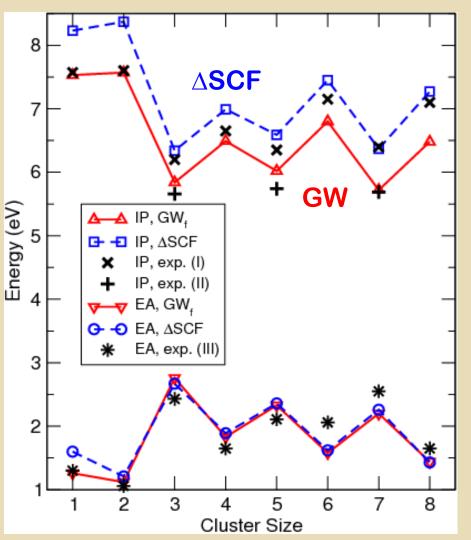
Systematic application and comparison of TDLDA and GWBSE in finite systems with tightly bound *d* electrons to investigate the role of *d* electrons in optical excitations.

Chose  $Ag_n$  (n = 1-8) as prototype clusters with shallow (but filled) *d* orbitals. [Tiago, Idrobo, Ogut et al. PRB 79, 155419 (2009)] Ongoing studies for Cu and Au clusters

## Electronic Excitations (IP and EA) Comparison with $\triangle$ SCF and Experiment



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- Within  $\triangle$ SCF *IP* = *E*(*n*-1) *E*(*n*) and *EA* = *E*(*n*) *E*(*n*+1).
- Within GW *IP = HOMO* and *EA = LUMO*.

• Generally quite good agreement of GW results with experiment (especially Ag and Ag<sub>2</sub>). Agreement not so good with  $\triangle$ SCF.

•  $\Sigma$  very sensitive to the number of virtual orbitals. Convergence accelerated by including a *static remainder* (estimate the numerical error by truncating the sum over virtual orbitals at the level of COHSEX).

		IP (e'	V)	EA (eV)		
	NS	ST	Exp	NS	ST	Exp
Ag	7.12	7.53	7.57	0.92	1.26	1.30
Ag <sub>2</sub>	6.27	7.54	7.60	0.82	1.12	1.06

(700 orbitals included in  $\Sigma$ )





• Observed good agreement at this level of theory due to the fact that HOMO and LUMO of Ag<sub>n</sub> ( $n \leq 8$ ) have almost entirely *sp* character (little or no *d* character). For example, in Ag<sub>2</sub>, HOMO is 92% *sp*, 8 % *d*, LUMO is 98 % *sp*, and 2% *d*.

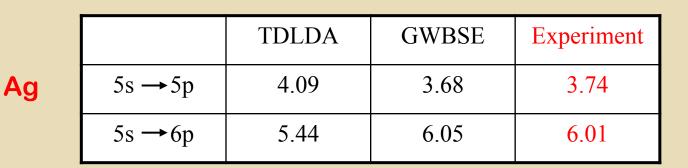
• Singly ionized Ag atom, Ag<sup>+</sup>, is a good test case for a system with large (entirely) *d* character in HOMO (and purely *s* character in LUMO!). IP of Ag<sup>+</sup> is the double IP of Ag, which is experimentally available. EA of Ag<sup>+</sup> is the IP of neutral Ag!

IP (eV)				EA (eV)		
	NS	ST	Exp	NS	ST	Exp
Ag <sup>+</sup>	16.64	18.92	21.50	7.34	7.64	7.57

• 2.6 eV underestimate of IP in Ag<sup>+</sup> (4*d* level) due to core-valence separation in the pseudopotential construction (standard  $4d^{10}5s^{1}5p^{0}$  reference). Though 4*s* and 4*p* levels are ~ 80 and 50 eV below the 4*d* level, due to their strong *spatial* overlap with 4*d* levels, exchange and correlation among 4*s*, 4*p*, and 4*d* electrons are not described properly by a Slater type exchange-correlation [Rohlfing et al. PRL 75, (1995)]

• **Remedy: Create semi-core pseudopotentials** by keeping 4*s* and 4*p* levels in the valence. Use the reference  $4s^24p^64d^{10}$  with *sp* core radii ~ 1.1 a.u. Very deep pseudopotentials. Use *h* = 0.2 a.u (limited tests)

	NS	ST	Exp	NS	ST	Exp
Ag <sup>+</sup> (semicore)	20.67	21.85	21.50	7.04	7.30	7.57



		TDLDA	GWBSE	Experiment
	A - X	3.11	2.54	2.85
<b>9</b> 2	B - X	3.96	3.99	4.44
	C - X	4.75	4.27	4.67

Ag

UIC

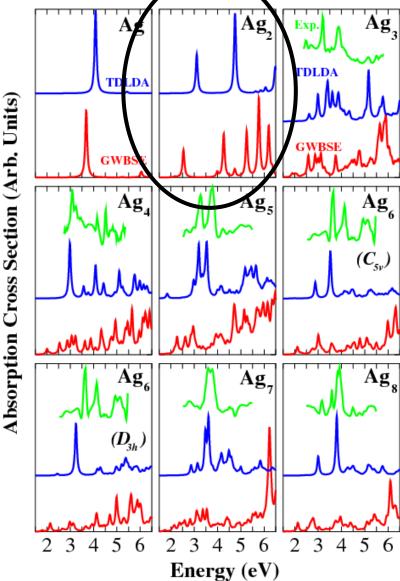
**GWBSE clearly performs well for Ag atom**. In Ag<sub>2</sub>, agreement with experiment not as good. TDLDA in slightly better agreement (perhaps).



#### Optical Excitations within GWBSE and TDDFT & Comparison with Experiment



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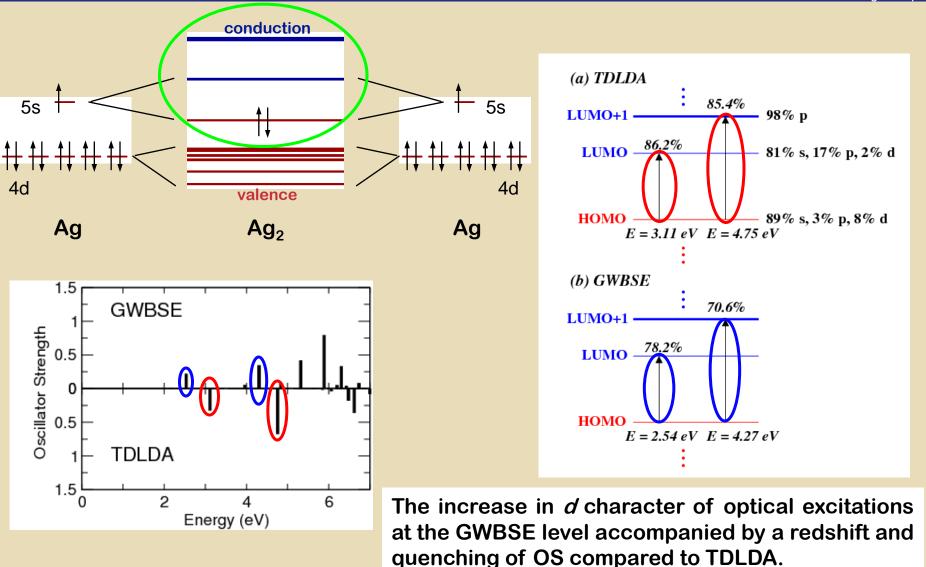


- For n >2, agreement between TDLDA and GWBSE very poor. At low energies, OS from GWBSE quenched significantly, above 5 eV, high OS transitions.
  - TDLDA has clearly better agreement with experimental data (esp. n = 5 - 8).
  - Exchange-correlation effects involving 4*d* orbitals and strong non-locality of the BSE kernel are the main reasons for this behavior.
  - Even a small mixture of d character results in significant quenching and redshifting of the predicted transitions at the GWBSE level, as best illustrated for the case of Ag<sub>2</sub>





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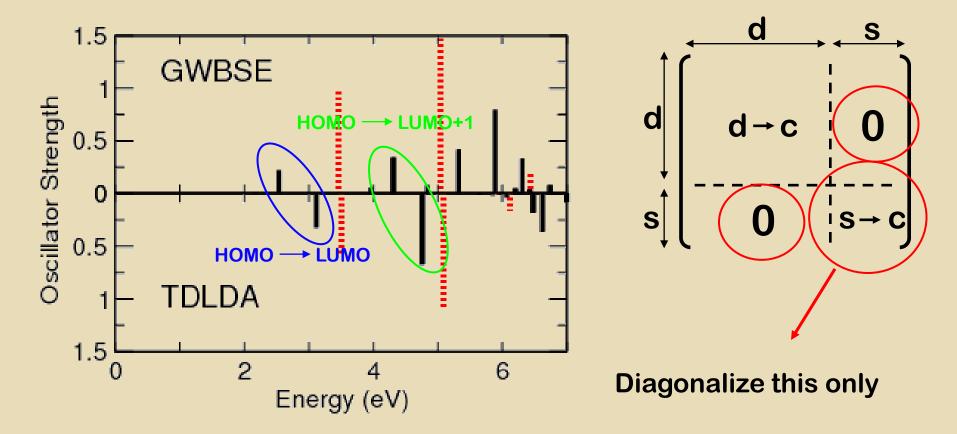


## **Thought experiment: "Remove" the** *d* electrons



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#### *d*: *v* = 1 - 10 *s*: *v* = 11 (HOMO)



## When *d* electrons are removed, very good agreement between TDLDA and GWBSE.